

Electrical Characteristics @ T_j = 25°C (Unless Otherwise Specified)

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions	
BV _{DSS}	Drain-to-Source Breakdown Voltage	-100			V	$V_{GS} = 0V, I_{D} = -250\mu A$	
$\Delta BV_{DSS}/\Delta T_{J}$	Breakdown Voltage Temp. Coefficient		-0.12		V/°C	Reference to 25°C, I _D = -1.0mA	
R _{DS(on)}	Static Drain-to-Source On-State Resistance			0.07	Ω	V _{GS} = -10V, I _{D2} = -21A ④	
$V_{GS(th)}$	Gate Threshold Voltage	-2.0		-4.0	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Gfs	Forward Transconductance	10			S	V _{DS} = -15V, I _{D2} = -21A ④	
I _{DSS}	Zero Gate Voltage Drain Current			-25	۸	$V_{DS} = -100V, V_{GS} = 0V$	
				-250	μA	$V_{DS} = -80V, V_{GS} = 0V, T_{J} = 125^{\circ}C$	
I _{GSS}	Gate-to-Source Leakage Forward			-100	nA	V _{GS} = -20V	
	Gate-to-Source Leakage Reverse			100	ПД	$V_{GS} = 20V$	
Q_{G}	Total Gate Charge			180		I _{D2} = -21A	
Q_GS	Gate-to-Source Charge			25	nC	V _{DS} = -80V	
Q_{GD}	Gate-to-Drain ('Miller') Charge			100		V _{GS} = -10V	
t _{d(on)}	Turn-On Delay Time			28		$V_{DD} = -50V$	
tr	Rise Time			150	no	$I_{D2} = -21A$ $R_G = 2.5\Omega$	
$t_{d(off)}$	Turn-Off Delay Time			100	ns		
t _f	Fall Time			120		V _{GS} = -10V	
Ls +L _D	Total Inductance		6.8		nH	Measured from Drain lead (6mm / 0.25 in from package) to Source lead (6mm/ 0.25 from package) with Source wire internally bonded from Source pin to Drain pad	
C _{iss}	Input Capacitance		2730			V _{GS} = 0V	
C _{oss}	Output Capacitance		824		pF	$V_{DS} = -25V$	
C _{rss}	Reverse Transfer Capacitance		465			f = 1.0 MHz	

Source-Drain Diode Ratings and Characteristics

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions	
Is	Continuous Source Current (Body Diode)			-34	Α		
I _{SM}	Pulsed Source Current (Body Diode) ①			-136	^		
V_{SD}	Diode Forward Voltage			-1.6	V	$T_J = 25^{\circ}C, I_S = -21A, V_{GS} = 0V$	
t _{rr}	Reverse Recovery Time			260	ns	$T_J = 25^{\circ}C$, $I_F = -21A$, $V_{DD} \le -30V$	
Q _{rr}	Reverse Recovery Charge			1.8	μC	di/dt = 100A/µs ④	
t _{on}	Forward Turn-On Time	Intrinsic turn-on time is negligible (turn-on is dominated by L _S +L _D)					

Thermal Resistance

Symbol	Parameter	Min.	Тур.	Max.	Units
$R_{\theta JC}$	Junction-to-Case			1.0	
$R_{\theta CS}$	Case -to-Sink		0.21		°C/W
$R_{\theta JA}$	Junction-to-Ambient (Typical socket mount)			48	

Footnotes:

- ① Repetitive Rating; Pulse width limited by maximum junction temperature.
- $@ V_{DD} = -25V, \ starting \ T_J = 25^{\circ}C, \ L = 2.4mH, \ Peak \ I_L = -21A, \ V_{GS} = -10V, R_G = 25\Omega.$
- $\label{eq:local_local_local_local} \ensuremath{ \Im } \quad I_{SD} \leq \text{-21A, di/dt} \leq \text{-400A/} \mu s, \ V_{DD} \leq \text{-100V, } T_J \leq 150^{\circ} C$
- 4 Pulse width \leq 300 µs; Duty Cycle \leq 2%.

2 2021-04-30



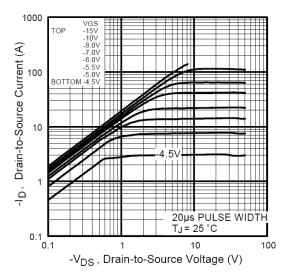


Fig 1. Typical Output Characteristics

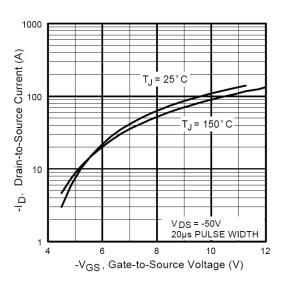


Fig 3. Typical Transfer Characteristics

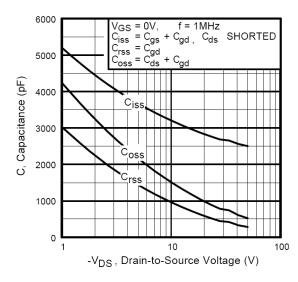


Fig 5. Typical Capacitance Vs. Drain-to-Source Voltage

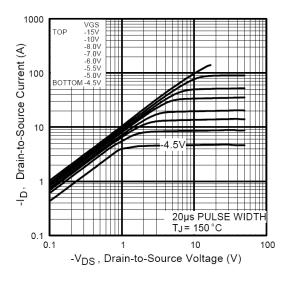


Fig 2. Typical Output Characteristics

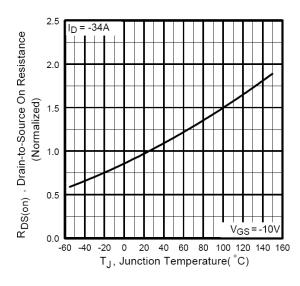


Fig 4. Normalized On-Resistance Vs. Temperature

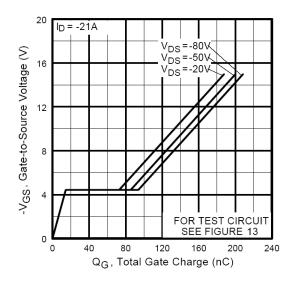


Fig 6. Typical Gate Charge Vs. Gate-to-Source Voltage

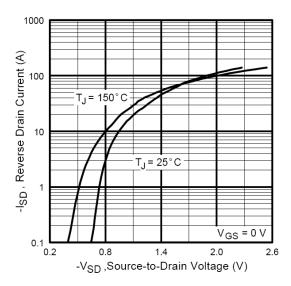


Fig 7. Typical Source-Drain Diode Forward Voltage

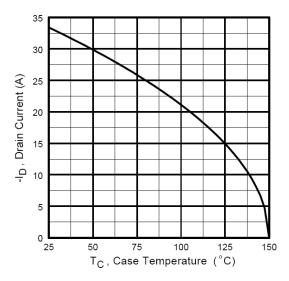


Fig 9. Maximum Drain Current Vs. Case Temperature

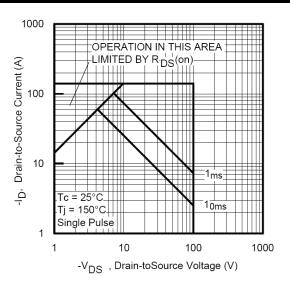


Fig 8. Maximum Safe Operating Area

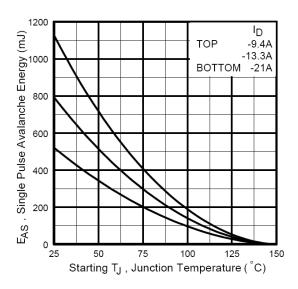


Fig 10. Maximum Avalanche Energy Vs. Drain Current

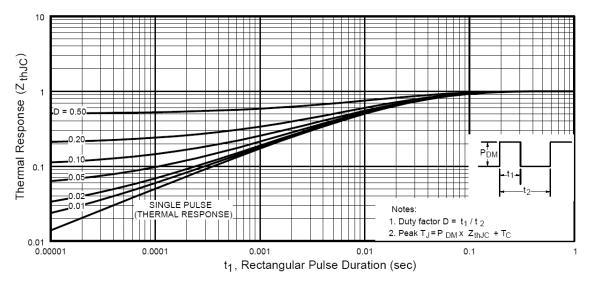


Fig 11. Maximum Effective Transient Thermal Impedance, Junction-to-Case

4

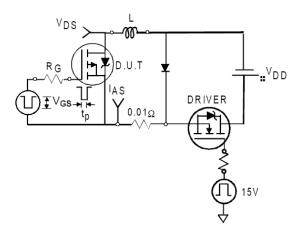


Fig 12a. Unclamped Inductive Test Circuit

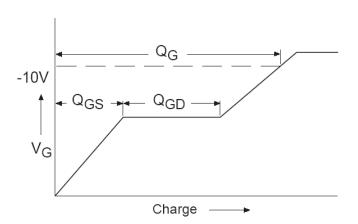


Fig 13a. Basic Gate Charge Waveform

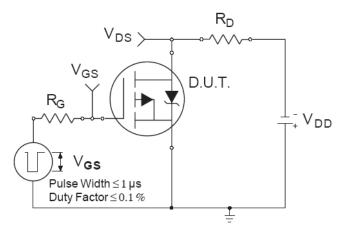


Fig 14a. Switching Time Test Circuit

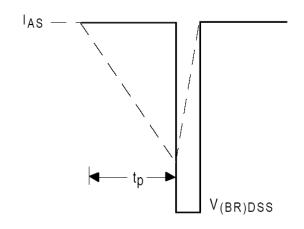


Fig 12b. Unclamped Inductive Waveforms

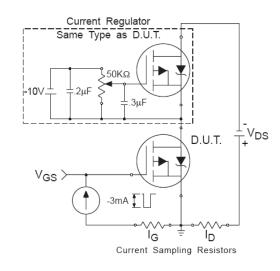


Fig 13b. Gate Charge Test Circuit

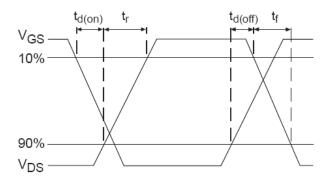
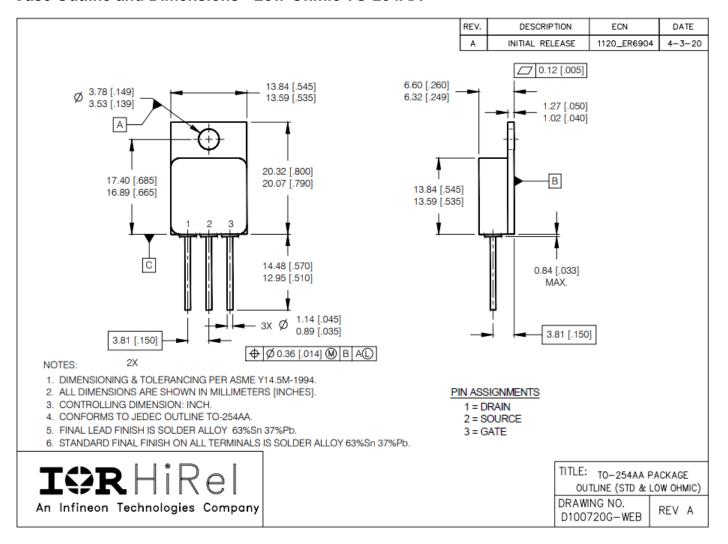


Fig 14b. Switching Time Waveforms



Note: For the most updated package outline, please see the website: TO-254AA

Case Outline and Dimensions - Low-Ohmic TO-254AA



BERYLLIA WARNING PER MIL-PRF-19500

Package containing beryllia shall not be ground, sandblasted, machined, or have other operations performed on them which will produce beryllia or beryllium dust. Furthermore, beryllium oxide packages shall not be placed in acids that will produce fumes containing beryllium.



www.infineon.com/irhirel

Infineon Technologies Service Center: USA Tel: +1 (866) 951-9519 and International Tel: +49 89 234 65555

Leominster, Massachusetts 01453, USA Tel: +1 (978) 534-5776

San Jose, California 95134, USA Tel: +1 (408) 434-5000

Data and specifications subject to change without notice.

6 2021-04-30



IMPORTANT NOTICE

The information given in this document shall be in no event regarded as guarantee of conditions or characteristic. The data contained herein is a characterization of the component based on internal standards and is intended to demonstrate and provide guidance for typical part performance. It will require further evaluation, qualification and analysis to determine suitability in the application environment to confirm compliance to your system requirements.

With respect to any example hints or any typical values stated herein and/or any information regarding the application of the product, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind including without limitation warranties on non- infringement of intellectual property rights and any third party.

In addition, any information given in this document is subject to customer's compliance with its obligations stated in this document and any applicable legal requirements, norms and standards concerning customer's product and any use of the product of Infineon Technologies in customer's applications.

The data contained in this document is exclusively intended for technically trained staff. It is the responsibility of any customer's technical departments to evaluate the suitability of the product for the intended applications and the completeness of the product information given in this document with respect to applications.

For further information on the product, technology, delivery terms and conditions and prices, please contact your local sales representative or go to (www.infineon.com/irhirel).

WARNING

Due to technical requirements products may contain dangerous substances. For information on the types in question, please contact your nearest Infineon Technologies office.

7 2021-04-30